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# **Operational Amplifiers, Dual Power, 1.0 A Output Current**

# TCA0372, TCA0372B, **NCV0372B**

The TCA0372 is a monolithic circuit intended for use as a power operational amplifier in a wide range of applications, including servo amplifiers and power supplies. No deadband crossover distortion provides better performance for driving coils.

### **Features**

- Output Current to 1.0 A
- Slew Rate of 1.3 V/µs
- Wide Bandwidth of 1.1 MHz
- Internal Thermal Shutdown
- Single or Split Supply Operation
- Excellent Gain and Phase Margins
- Common Mode Input Includes Ground
- Zero Deadband Crossover Distortion
- NCV devices are AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

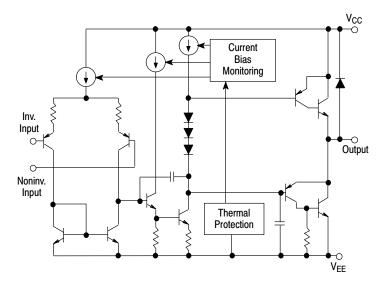
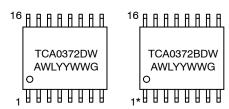


Figure 1. Representative Block Diagram



SOIC-16W **DW SUFFIX CASE 751G** 

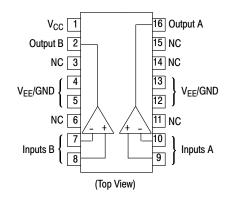
## **MARKING DIAGRAMS**



\*Also applies to NCV0372BDWR2G.

= Assembly Location WL = Wafer Lot ΥY = Year WW = Work Week = Pb-Free Package

### **PIN CONNECTIONS**



### ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

1

## **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Supply Voltage (from V <sub>CC</sub> to V <sub>EE</sub> )	V <sub>S</sub>	40	V
Input Differential Voltage Range	V <sub>IDR</sub>	Note 1	V
Input Voltage Range	V <sub>IR</sub>	Note 1	V
Junction Temperature (Note 2)	T <sub>J</sub>	+150	°C
Operating Temperature Range	T <sub>A</sub>	-40 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	−55 to +150	°C
DC Output Current	I <sub>O</sub>	1.0	Α
Peak Output Current (Nonrepetitive)	I <sub>(max)</sub>	1.5	Α
Thermal Resistance, Junction-to-Air	$R_{ hetaJA}$	80	°C/W
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	12	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Either or both input voltages should not exceed the magnitude of V<sub>CC</sub> or V<sub>EE</sub>.

2. Power dissipation must be considered to ensure maximum junction temperature (T<sub>J</sub>) is not exceeded.

**DC ELECTRICAL CHARACTERISTICS** ( $V_{CC}$  = +15 V,  $V_{EE}$  = -15 V,  $R_L$  connected to ground,  $T_A$  = -40° to +125°C.)

Characteristics		Symbol	Min	Тур	Max	Unit
Input Offset Voltage ( $V_{CM} = 0$ ) $T_A = +25^{\circ}C$ $T_{A}, T_{low} \text{ to } T_{high}$		V <sub>IO</sub>	- -	1.0	15 20	mV
Average Temperature Coefficient of Offset Voltage		$\Delta V_{IO}/\Delta T$	_	20	_	μV/°C
Input Bias Current (V <sub>CM</sub> = 0)		I <sub>IB</sub>	_	100	500	nA
Input Offset Current (V <sub>CM</sub> = 0)		I <sub>IO</sub>	_	10	50	nA
Large Signal Voltage Gain $V_0 = \pm 10 \text{ V}, R_L = 2.0 \text{ k}$		A <sub>VOL</sub>	30	100	-	V/mV
Output Voltage Swing ( $I_L$ = 100 mA) $T_A = +25^{\circ}C$ $T_A = T_{low} \text{ to } T_{high}$ $T_A = +25^{\circ}C$ $T_A = T_{low} \text{ to } T_{high}$		V <sub>OH</sub>	14.0 13.9 - -	14.2 - -14.2 -	- - -14.0 -13.9	V
$ \begin{array}{l} \text{Output Voltage Swing (I$_L$ = 1.0 A)} \\ \text{V$_{CC}$ = +24 V, V$_{EE}$ = 0 V, T$_A$ = +25°C} \\ \text{V$_{CC}$ = +24 V, V$_{EE}$ = 0 V, T$_A$ = T$_{low}$ to T$_{high}$} \\ \text{V$_{CC}$ = +24 V, V$_{EE}$ = 0 V, T$_A$ = +25°C} \\ \text{V$_{CC}$ = +24 V, V$_{EE}$ = 0 V, T$_A$ = T$_{low}$ to T$_{high}$} \end{array} $		V <sub>OH</sub>	22.5 22.5 - -	22.7 - 1.3 -	- - 1.5 1.6	V
Input Common Mode Voltage Range $T_A = +25^{\circ}C$ $T_A = T_{low}$ to $T_{high}$		V <sub>ICR</sub>	V <sub>EE</sub> to (V <sub>CC</sub> -1.0) V <sub>EE</sub> to (V <sub>CC</sub> -1.3)		V	
Common Mode Rejection Ratio (R <sub>S</sub> = 10 k)		CMRR	70	90	_	dB
Power Supply Rejection Ratio ( $R_S = 100 \Omega$ )		PSRR	70	90	_	dB
Power Supply Current $T_A = +25^{\circ}C$ $T_A = T_{low} \text{ to } T_{high}$	TCA0372 TCA0372B/NCV0372B TCA0372 TCA0372B/NCV0372B	I <sub>D</sub>	- - -	5.0 8.0 - -	10 10 14 14	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# AC ELECTRICAL CHARACTERISTICS ( $V_{CC}$ = +15 V, $V_{EE}$ = -15 V, $R_L$ connected to ground, $T_A$ = +25°C, unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Slew Rate ( $V_{in}$ = -10 V to +10 V, $R_L$ = 2.0 k, $C_L$ = 100 pF) $A_V$ = -1.0, $T_A$ = $T_{low}$ to $T_{high}$	SR	1.0	1.4	ı	V/μs
Gain Bandwidth Product (f = 100 kHz, $C_L$ = 100 pF, $R_L$ = 2.0 k) $T_A = 25^{\circ}C$ $T_A = T_{low} \text{ to } T_{high}$	GBW	0.9 0.7	1.4 -	1 1	MHz
Phase Margin $T_J = T_{low}$ to $T_{high}$ $R_L = 2.0 \text{ k}, C_L = 100 \text{ pF}$	фm	-	65	1	Degrees
Gain Margin $R_L = 2.0 \text{ k}, C_L = 100 \text{ pF}$	A <sub>m</sub>	_	15	ı	dB
Equivalent Input Noise Voltage $R_S = 100~\Omega,  f = 1.0  \text{to}   100  \text{kHz}$	e <sub>n</sub>	-	22	-	nV/√Hz
Total Harmonic Distortion $A_V = -1.0, R_L = 50\;\Omega, V_O = 0.5\;VRMS, f = 1.0\;kHz$	THD	_	0.02	-	%

NOTE: In case  $V_{\text{EE}}$  is disconnected before  $V_{\text{CC}}$ , a diode between  $V_{\text{EE}}$  and Ground is recommended to avoid damaging the device.

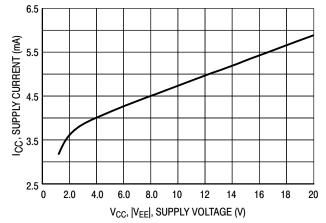


Figure 2. Supply Current versus Supply Voltage with No Load

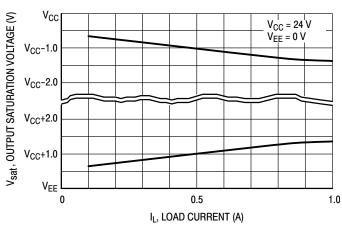


Figure 3. Output Saturation Voltage versus Load Current

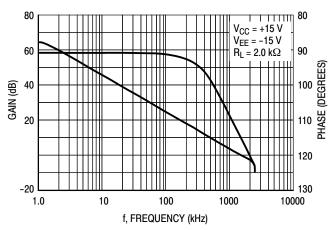


Figure 4. Voltage Gain and Phase versus Frequency

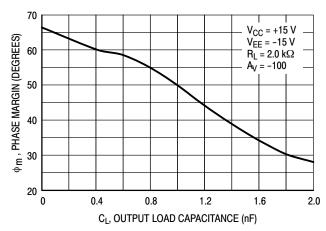


Figure 5. Phase Margin versus Output Load Capacitance

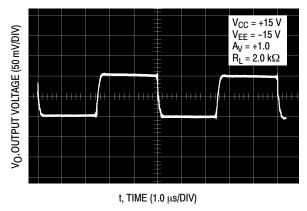


Figure 6. Small Signal Transient Response

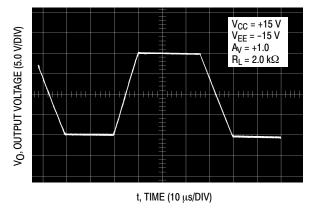


Figure 7. Large Signal Transient Response

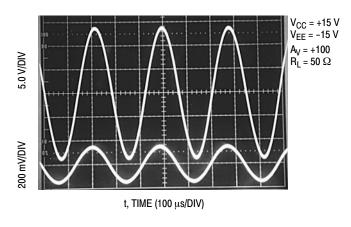


Figure 8. Sine Wave Response

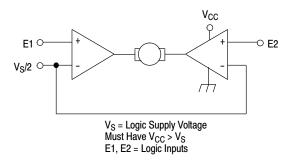
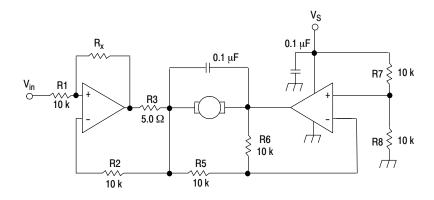


Figure 9. Bidirectional DC Motor Control with Microprocessor-Compatible Inputs



For circuit stability, ensure that  $R_X > \frac{2R3 \cdot R1}{R_M}$  where,  $R_M$  = internal resistance of motor. The voltage available at the terminals of the motor is:  $V_M = 2 (V_1 - \frac{V_S}{2}) + |R_0| \cdot I_M$  where,  $|R_0| = \frac{2R3 \cdot R1}{R_X}$  and  $I_M$  is the motor current.

Figure 10. Bidirectional Speed Control of DC Motors

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
TCA0372DWR2G	SOIC-16W (Pb-Free)	1000 / Tape & Reel
TCA0372BDWR2G	SOIC-16W (Pb-Free)	1000 / Tape & Reel
NCV0372BDWR2G*	SOIC-16W (Pb-Free)	1000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>AEC-Q100 Qualified and PPAP Capable



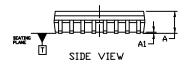


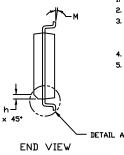
SOIC-16 WB CASE 751G ISSUE E

**DATE 08 OCT 2021** 



SCALE 1:1 **♦** 0.25**₩** B**₩** RRRR PIN 1 --INDICATOR -16X R **♦** 0.25**®** TAS BS TOP VIEW





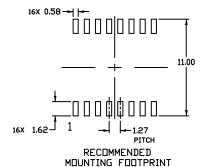


DETAIL A

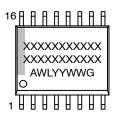
#### NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS
- DIMENSION 6 DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
- MAXIMUM MOLD PROTRUSION OR FLASH TO BE 0.15 PER SIDE.

	MILLIMETERS		
DIM	MIN.	MAX.	
Α	2.35	2.65	
A1	0.10	0.25	
В	0.35	0.49	
С	0.23	0.32	
D	10.15	10.45	
E	7.40	7.60	
е	1.27 BSC		
Н	10.05	10.55	
h	0.53 REF		
١	0.50	0.90	
М	0*	7*	



**GENERIC MARKING DIAGRAM\*** 



XXXXX = Specific Device Code = Assembly Location

WL = Wafer Lot YY = Year ww = Work Week G = Pb-Free Package

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